

Ordering Information

		mum us Current		ort-circuit nt Limit	Enable		Output		
Part Number	Channel 1	Channel 2	Channel 1	Channel 2	Setting	Package	Discharge	Environmental	
AOZ1341AI					Active Low	SO-8			
AOZ1341EI	1 A	1 A 1 1A	1.5 A	4.5.4	Active Low	EPAD MSOP-8			
AOZ1341AI-1	TA TA	1.5 A	1.5 A	Active High	SO-8				
AOZ1341EI-1					Active right	EPAD MSOP-8			
AOZ1342PI	1.5 A	1.5A	2.4	2 A 2 A - 2 A - 2 A - 2 A None	Active Low	EPAD SO-8		Green Product RoHS Compliant	
AOZ1342PI-1	1.5 A	I.5A	2 A		Active High	EPAD SO-8			
AOZ1343AI*					A ativa Law	SO-8	No		
AOZ1343EI*	1.5 A 0.5A		2.4		0.75 A	Active Low	EPAD MSOP-8		rtorro compilant
AOZ1343AI-1*			Z A				0.75 A	Active High	SO-8
AOZ1343EI-1*					Active right		EPAD MSOP-8		
AOZ1312AI-1	1.5 A	None	0.4		Active High	SO-8			
AOZ1312EI-1	1.3 A	ivone	2 A		Active night	EPAD MSOP-8			
AOZ1310CI-1	0.5 A	None	0.75 A	None	Active High	SOT23-5			

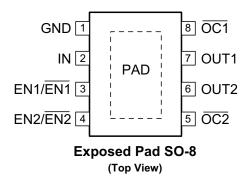
^{*}Contact factory for availability



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

 $Please\ visit\ www.aosmd.com/web/quality/rohs_compliant.jsp\ for\ additional\ information.$

Pin Configuration



Pin Description

Pin Name	Pin Number	Pin Function
GND	1	Ground
IN	2	Input voltage
EN1/EN1	3	Enable input, logic high/logic low turns on power switch IN-OUT1
EN2/EN2	4	Enable input, logic high/logic low turns on power switch IN-OUT2
OC2	5	Overcurrent, open-drain output, active low, IN-OUT1
OUT2	6	Power-switch output, IN-OUT1
OUT1	7	Power-switch output, IN-OUT2
OC1	8	Overcurrent, open-drain output, active low, IN-OUT2

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Absolute Maximum Ratings

Exceeding the Absolute Maximum Ratings may damage the device.

Parameter	Rating
Input Voltage (V _{IN})	6 V
Enable Voltage (V _{EN})	6 V
Storage Temperature (T _S)	-55 °C to +150 °C
Maximum Continuous Current	1.5 A
ESD Rating ⁽¹⁾	2 kV

Note:

Recommended Operating Conditions

The device is not guaranteed to operate beyond the Recommended Operating Conditions.

Parameter	Rating
Input Voltage (V _{IN})	+2.7 V to +5.5 V
Junction Temperature (T _J)	-40 °C to +125 °C
Package Thermal Resistance	
Exposed Pad SO-8 (⊕ _{JA})	45 °C/W

Electrical Characteristics

 $T_A = 25 \,^{\circ}\text{C}$, $V_{IN} = V_{EN} = 5.5 \,\text{V}$, unless otherwise specified.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units	
POWER S	WITCH					·	
R _{DS(ON)}	Switch On-Resistance		70	135	mΩ		
t _r	Rise Time, Output	V _{IN} = 5.5 V		0.6	1.5	ms	
		V _{IN} = 2.7 V			0.4	1	
t _f	Fall time, Output	V _{IN} = 5.5 V	0.05		0.5	ms	
		V _{IN} = 2.7 V	0.05		0.5		
	FET Leakage Current	Out connect to ground, $2.7 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V},$ $\text{V}_{(\overline{\text{ENx}})} = \text{V}_{\text{IN}} \text{ or V}_{(ENx)} = 0 \text{ V}$	$-40 \text{ °C} \le T_{J} \le 125 \text{ °C}^{(2)}$		1		μА
ENABLE I	NPUT EN OR EN				•		
V _{IH}	High-level Input Voltage	2.7 V ≤ V _{IN} ≤ 5.5 V	2.0			V	
V _{IL}	Low-level Input Voltage	$2.7 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}$			0.8	V	
I _I	Input Current		-0.5		0.5	μΑ	
t _{on}	Turn-on Time	$C_L = 100 \mu F, R_L = 5 \Omega$			3	ms	
t _{off}	Turn-off Time	$C_L = 100 \mu F, R_L = 5 \Omega$			10		
CURRENT	LIMIT				•	•	
I _{OS}	Short-circuit Output Current (per Channel)	V _(IN) = 2.7 V to 5.5 V, OUT connected to GND, device enable into short-circuit, Channel 1 or 2			2.0	2.4	A
I _{OC_TRIP}	Overcurrent Trip Threshold (per Channel)	V _(IN) = 5 V, current ramp (≤ 10 Channel 1 or 2	0 A/s) on OUT,	1.6	2.2	2.5	Α
SUPPLY (CURRENT					l.	l.
	Supply Current, Low-level	No load on OUT,	T _J = 25°C		0.5	1	μА
	Output	$ 2.7 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, $ $\text{V}_{(\overline{\text{ENx}})} = \text{V}_{\text{IN}} \text{ or } \text{V}_{(\text{ENx})} = 0 \text{ V} $	$-40 \text{ °C} \le T_{\text{J}} \le 125 \text{ °C}^{(2)}$		0.5	5	
	Supply current, High-level	No load on OUT,	T _J = 25 °C		65	81	μА
	Output	$V_{(\overline{ENx})} = 0 \text{ V or } V_{(ENx)} = 5.5 \text{ V}$	$-40 \text{ °C} \le T_{\text{J}} \le 125 \text{ °C}^{(2)}$		65	90	
	Reverse Leakage Current	$V_{(OUTx)} = 5.5 \text{ V}, \text{ IN = ground}$			0.2		μΑ

^{1.} Devices are inherently ESD sensitive, handling precautions are required. Human body model is a 100 pF capacitor discharging through a 1.5 k Ω resistor.



Electrical Characteristics (Continued)

 T_A = 25 °C, V_{IN} = V_{EN} = 5.5 V, unless otherwise specified.

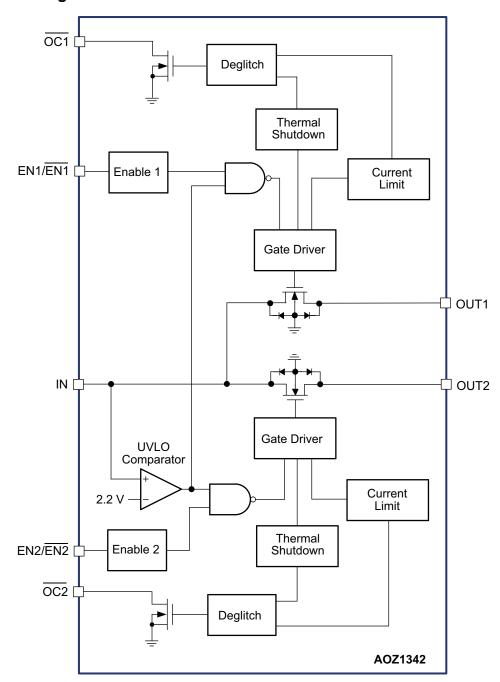
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
UNDERVO	LTAGE LOCKOUT			'		
	Low-level voltage, IN		2.0		2.5	V
	Hysteresis, IN			200		mV
OVERCUR	RENT OC1 AND OC2					
	Output Low Voltage V _{OL(OCx)}	$I_{O(OCx)} = 5 \text{ mA}$			0.4	V
	Off-state Current	V _{O(OCx)} = 5 V or 3.3 V			1	μΑ
	OC_L Deglitch	OCx assertion or deassertion	4	8	15	ms
THERMAL	SHUTDOWN					
	Thermal Shutdown Threshold		135			°C
	Recovery from Thermal Shutdown		105			°C
	Hysteresis			30		°C

Note:

^{2.} Parameters are guaranteed by design only and not production tested.



Functional Block Diagram





Functional Characteristics

Figure 1. Turn-On Delay and Rise Time

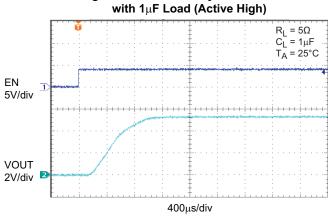


Figure 2. Turn-Off Delay and Fall Time with 1μF Load (Active High)

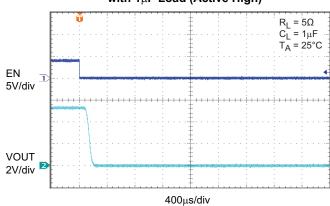


Figure 3. Turn-On Delay and Rise Time with 100μF Load (Active High)

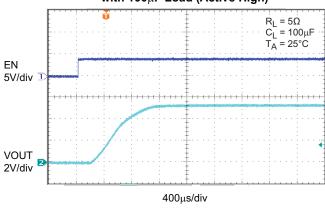


Figure 4. Turn-Off Delay and Fall Time with 100μF Load (Active High)

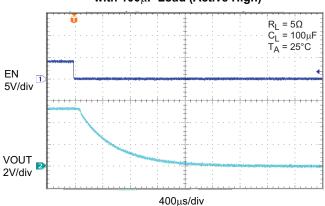


Figure 5. Short-circuit Current, Device Enable to Short (Active High)

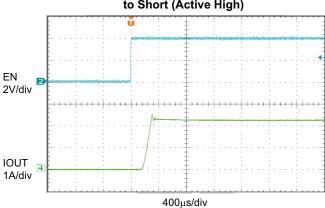
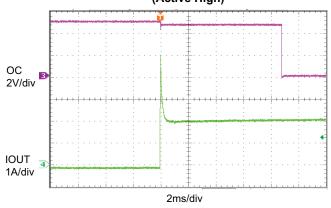


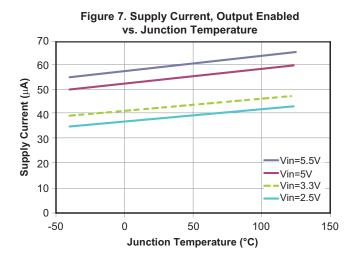
Figure 6. 0.6Ω Load Connected to Enable to Device (Active High)

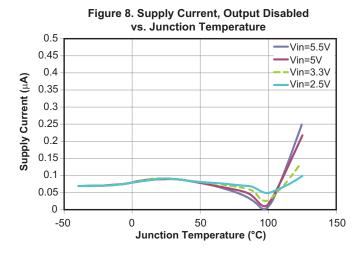


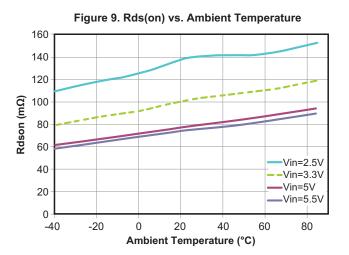
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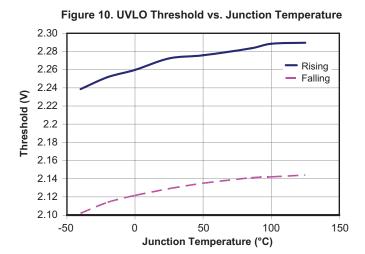


Typical Characteristics









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Detailed Description

The AOZ1342 family of power-distribution switches are intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. This device incorporates 70 m Ω N-channel MOSFET power switches for power-distribution systems that require multiple power switches in a single package. Each switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

Thermal Shut-down Protection

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent (OC) logic output low.

During current limit or short circuit conditions, the increasing power dissipation in the chip causes the die temperature to rise. When the die temperature reaches a certain level, the thermal shutdown circuitry will shutdown the device. The thermal shutdown will cycle repeatedly until the short circuit condition is resolved.

Applications Information

Input Capacitor Selection

The input capacitor prevents large voltage transients from appearing at the input, and provides the instantaneous current needed each time the switch turns on and to also limit input voltage drop. The input capacitor also prevents high-frequency noise on the power line from passing through the output of the power side. The choice of input capacitor is based on its ripple current and voltage ratings rather than its capacitor value. The input capacitor should be located as close as possible to the VIN pin. A 0.1 μF ceramic cap is recommended. However, a higher value capacitor will reduce the voltage drop at the input.

Output Capacitor Selection

The output capacitor acts in a similar way. A small 0.1 μF capacitor prevents high-frequency noise from going into the system. Also, the output capacitor has to supply enough current for the large load that it may encounter during system transients. This bulk capacitor must be large enough to supply a fast transient load in order to prevent the output from dropping.

Power Dissipation Calculation

Calculate the power dissipation for normal load condition using the following equation:

$$P_D = R_{ON} \times (I_{OUT})^2$$

The worst case power dissipation occurs when the load current hits the current limit due to over-current or short circuit faults. The power dissipation under these conditions can be calculated using the following equation:

$$P_D = (V_{IN} - V_{OUT}) \times I_{LIMIT}$$

Layout Guidelines

Good PCB layout is important for improving the thermal and overall performance of AOZ1342. To optimize the switch response time to output short-circuit conditions, keep all traces as short as possible to reduce the effect of unwanted parasitic inductance. Place the input and output bypass capacitors as close as possible to the IN and OUT pins. The input and output PCB traces should be as wide as possible for the given PCB space. Use a ground plane to enhance the power dissipation capability of the device.



USB Power Distribution Application

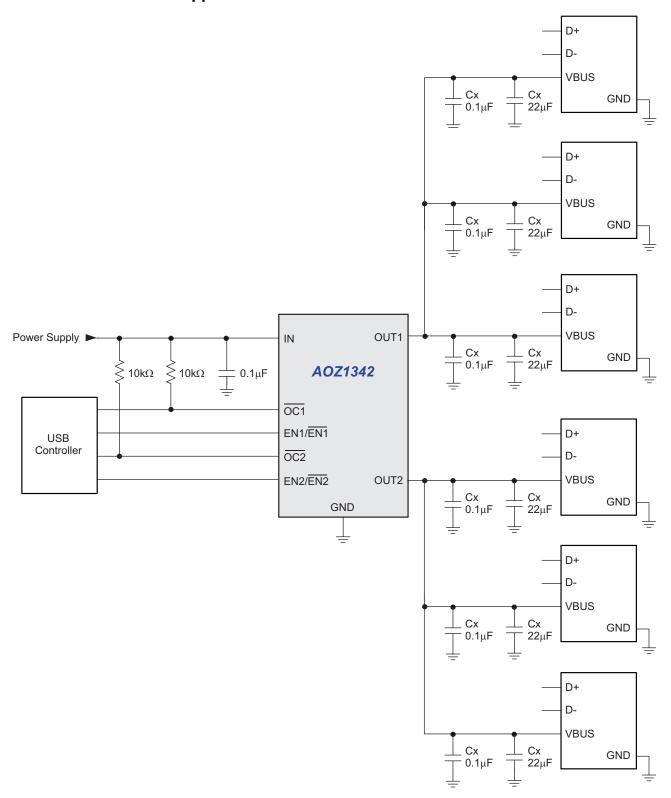
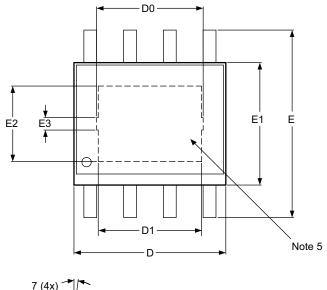


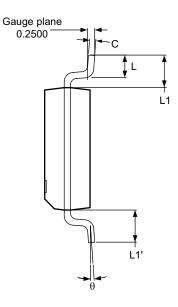
Figure 11. Typical Six-Port USB Host/Self-Powered Hub Applications Circuitry

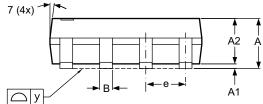
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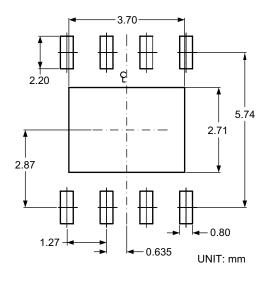
Package Dimensions, Exposed Pad SO-8







RECOMMENDED LAND PATTERN



Dimensions in millimeters

Symbols	Min.	Nom.	Max.				
Α	1.40	1.55	1.70				
A1	0.00	0.05	0.10				
A2	1.40	1.50	1.60				
В	0.31	0.406	0.51				
С	0.17	_	0.25				
D	4.80	4.96	5.00				
D0	3.20	3.40	3.60				
D1	3.10	3.30	3.50				
Е	5.80	6.00	6.20				
е	_	1.27	_				
E1	3.80	3.90	4.00				
E2	2.21	2.41	2.61				
E3	(0.40 REF	=				
L	0.40	0.95	1.27				
У	_	_	0.10				
θ	0°	3°	8°				
L1–L1'	_	0.04	0.12				
L1	1.04 REF						

Dimensions in inches

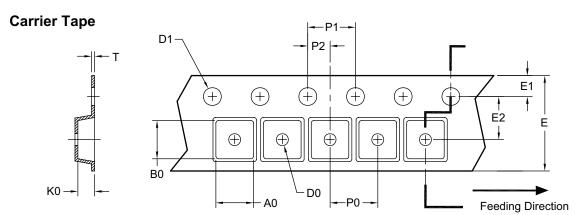
Symbols	Min.	Nom.	Max.			
Α	0.055	0.061	0.067			
A1	0.000	0.002	0.004			
A2	0.055	0.059	0.063			
В	0.012	0.016	0.020			
С	0.007	_	0.010			
D	0.189	0.195	0.197			
D0	0.126	0.134	0.142			
D1	0.122	0.130	0.138			
E	0.228	0.236	0.244			
е	_	0.050	_			
E1	0.150	0.153	0.157			
E2	0.087	0.095	0.103			
E3	0	.016 RE	F			
L	0.016	0.037	0.050			
у	_	_	0.004			
θ	0°	3°	8°			
L1–L1'		0.002	0.005			
L1	0.041 REF					

Notes:

- 1. Package body sizes exclude mold flash and gate burrs.
- 2. Dimension L is measured in gauge plane.
- 3. Tolerance 0.10mm unless otherwise specified.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.
- 5. Die pad exposure size is according to lead frame design.
- 6. Followed from JEDEC MS-012

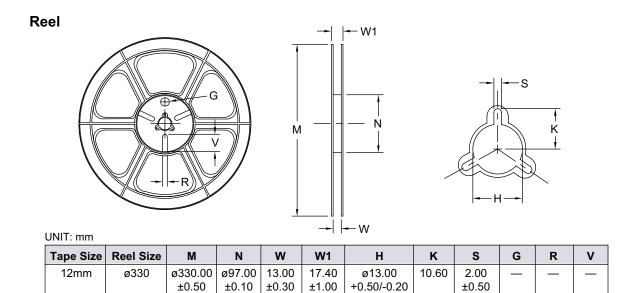


Tape and Reel Dimensions, Exposed Pad SO-8

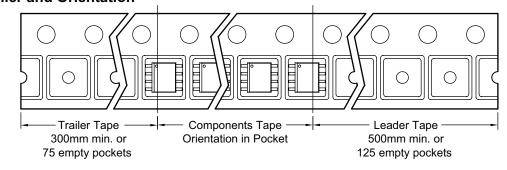


UNIT: mm

Package	A0	В0	K0	D0	D1	Е	E1	E2	P0	P1	P2	T
SO-8	6.40	5.20	2.10	1.60	1.50	12.00	1.75	5.50	8.00	4.00	2.00	0.25
(12mm)	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10



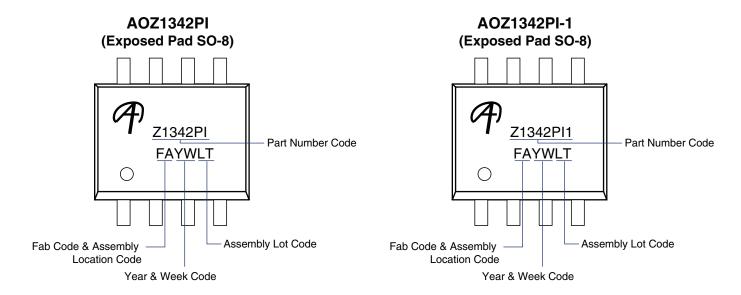
Leader/Trailer and Orientation



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Part Marking



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